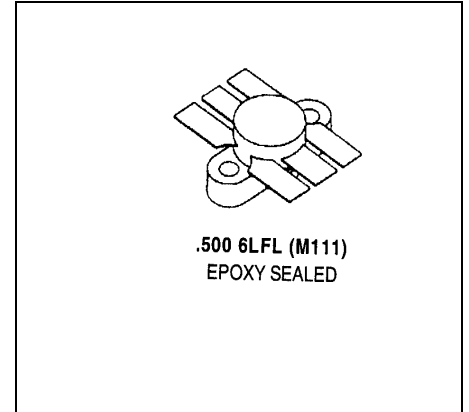


## MS1511

### RF & MICROWAVE TRANSISTORS UHF COMMUNICATIONS APPLICATIONS

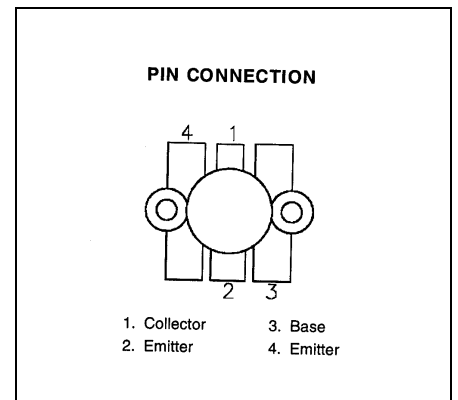
#### Features

- 400 MHz
- 28 VOLTS
- $P_{OUT} = 70$  WATTS
- $G_P = 8.4$  dB GAIN MINIMUM
- EFFICIENCY 60%
- GOLD METALLIZATION
- COMMON EMITTER CONFIGURATION



#### DESCRIPTION:

The MS1511 is a 28 V Class C epitaxial silicon NPN planar transistor designed primarily for UHF communications. This device utilizes diffused emitter resistors to achieve VSWR of 10:1 under operating conditions, and is internally input matched to optimize power gain and efficiency over the 225 – 400 MHz band.



#### ABSOLUTE MAXIMUM RATINGS (T<sub>case</sub> = 25°C)

Symbol	Parameter	Value	Unit
V <sub>CB0</sub>	Collector-Base Voltage	60	V
V <sub>CEO</sub>	Collector-Emitter Voltage	30	V
V <sub>EBO</sub>	Emitter-Base Voltage	4.0	V
I <sub>C</sub>	Device Current	8.0	A
P <sub>DISS</sub>	Power Dissipation	220	W
T <sub>J</sub>	Junction Temperature	+200	°C
T <sub>STG</sub>	Storage Temperature	-65 to +150	°C

#### Thermal Data

R <sub>TH(J-C)</sub>	Thermal Resistance Junction-case	1.25	°C/W
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## ELECTRICAL SPECIFICATIONS (T<sub>case</sub> = 25°C)

### STATIC

Symbol	Test Conditions		Value			Unit
			Min.	Typ.	Max.	
BV <sub>CBO</sub>	I <sub>C</sub> = 50 mA	I <sub>E</sub> = 0mA	60	---	---	V
BV <sub>CEO</sub>	I <sub>E</sub> = 50 mA	I <sub>B</sub> = 0 mA	30	---	---	V
BV <sub>EBO</sub>	I <sub>C</sub> = 10 mA	I <sub>C</sub> = 0mA	4.0	---	---	V
I <sub>CBO</sub>	V <sub>CB</sub> = 30 V	I <sub>E</sub> = 0 mA	---	---	5	mA
HFE	V <sub>CE</sub> = 5 V	I <sub>C</sub> = 2 A	20	---	80	---

### DYNAMIC

Symbol	Test Conditions			Value			Unit
				Min.	Typ.	Max.	
P <sub>OUT</sub>	f = 400 MHz	P <sub>IN</sub> = 10 W	V <sub>CE</sub> = 28 V	70	---	---	W
G <sub>P</sub>	f = 400 MHz	P <sub>IN</sub> = 10 W	V <sub>CE</sub> = 28 V	8.4	---	---	dB
C <sub>OB</sub>	f = 1 MHz	V <sub>CB</sub> = 28 V		---	---	80	pF

### IMPEDANCE DATA

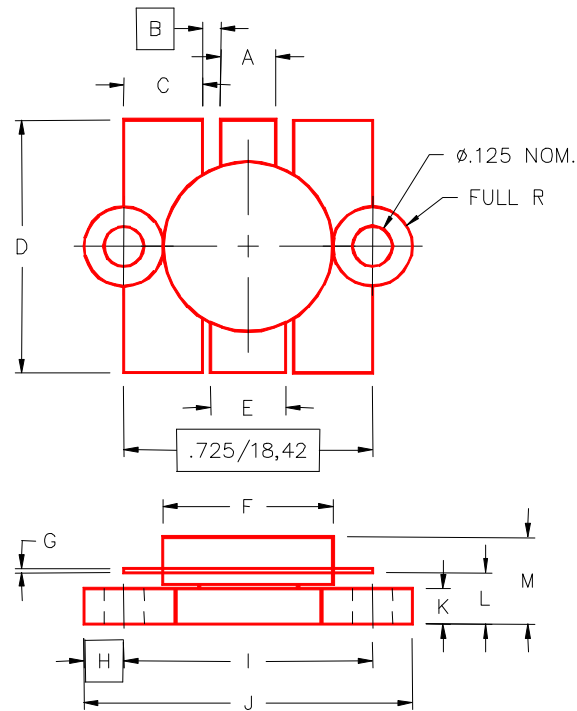
FREQ	Z <sub>IN</sub> (Ω)	Z <sub>CL</sub> (Ω)
225 MHz	1.44 - j0.87	1.70 - j2.6
400 MHz	1.29 + j0.87	3.0 + j0.87

P<sub>IN</sub> = 10W

V<sub>CC</sub> = 28V

**PACKAGE MECHANICAL DATA**

PACKAGE STYLE M111



	MINIMUM INCHES/MM	MAXIMUM INCHES/MM		MINIMUM INCHES/MM	MAXIMUM INCHES/MM
A	.150/3,43	.160/4,06	I	.720/18,29	.730/18,54
B	.045/1,14		J	.970/24,64	.980/24,89
C	.210/5,33	.220/5,59	K	.095/2,41	.105/2,67
D	.835/21,21	.865/21,97	L	.150/3,81	.170/4,32
E	.200/5,08	.210/5,33	M		.280/7,11
F	.490/12,45	.510/12,95			
G	.003/0,08	.007/0,18			
H	.125/3,18				